



MONARCH
Antenna, Inc.

Reshaping Wireless

**Frequency Tunable Antenna for LTE (4G) Handsets
Operating in the 2.3–2.7GHz Global Roaming Band**

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Long Term Evolution (LTE), a.k.a. 4G

- Better spectrum efficiency,
 - Higher data rates,
 - Lower latencies, and
 - Flatter IP core network architecture
-
- CHALLENGE:
 - LTE Spectrum is fragmented
 - Carrier Aggregation

Case for Tunable Antenna

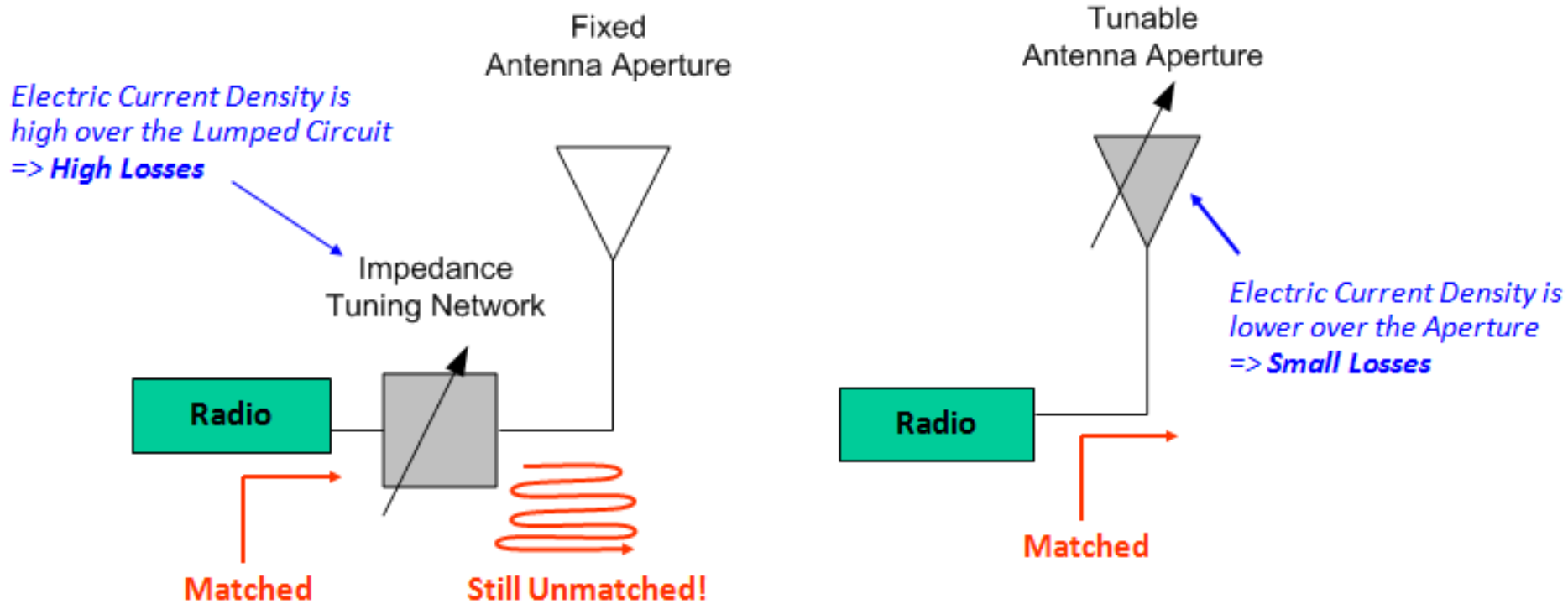
- Searching for a Global Roaming Band
- Not about having one phone to roam globally
- But about having fewer Stock Keeping Units (SKUs)
- The International Wireless Industry Consortium (IWPC) Working Group for tunable RF front-end (RFFE)
 - Architecture for an Integrated RFFE module
 - 2.3-2.7GHz is suggested as the **global roaming band** with the potential to reach 55% of the world's population.
 - A Tunable RFFE will need a Tunable Antenna

Presentation Flow

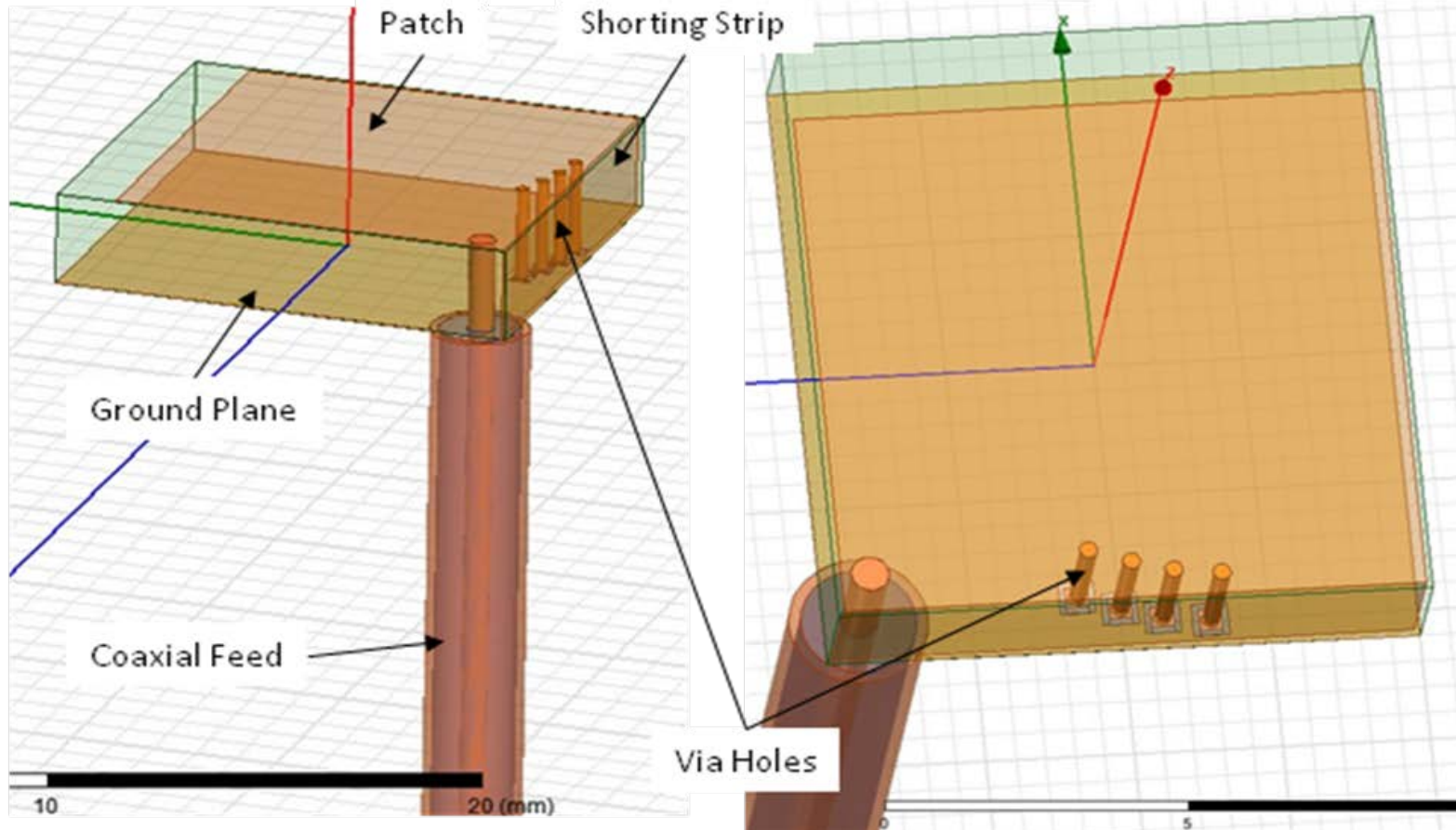
- Impedance Tuning vs. Aperture Tuning
- Design
- Manufacturing
- Measured Data



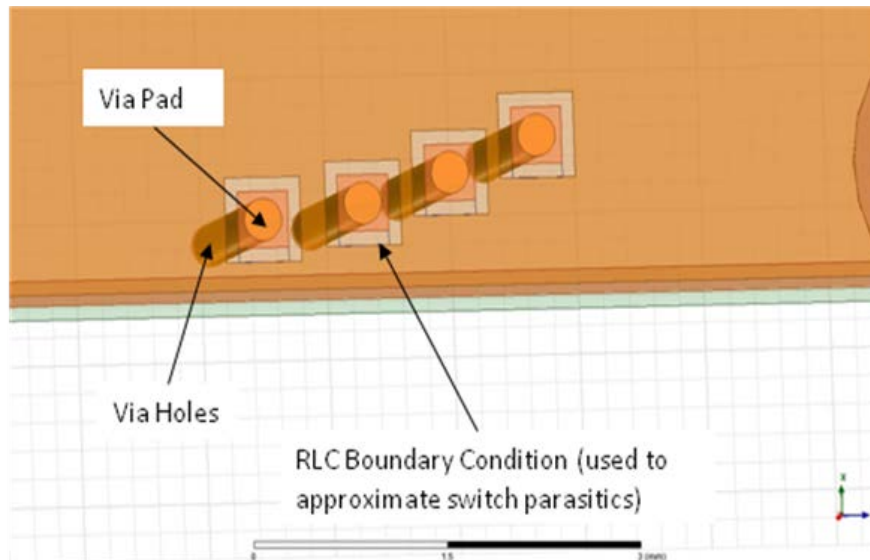
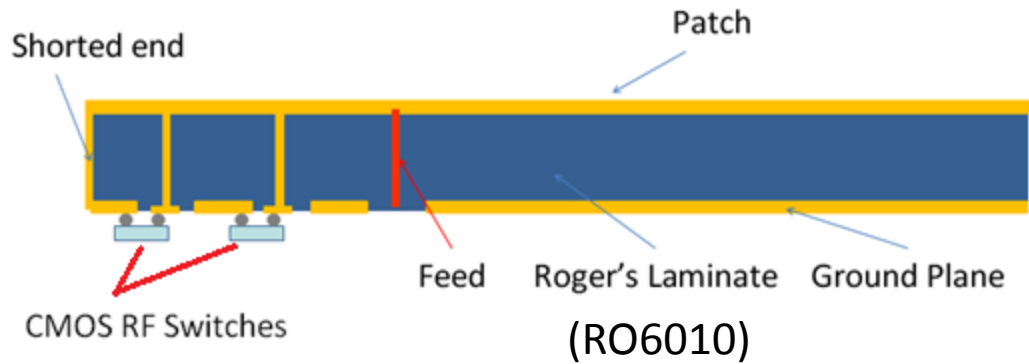
Impedance Tuning vs. Aperture Tuning



Design

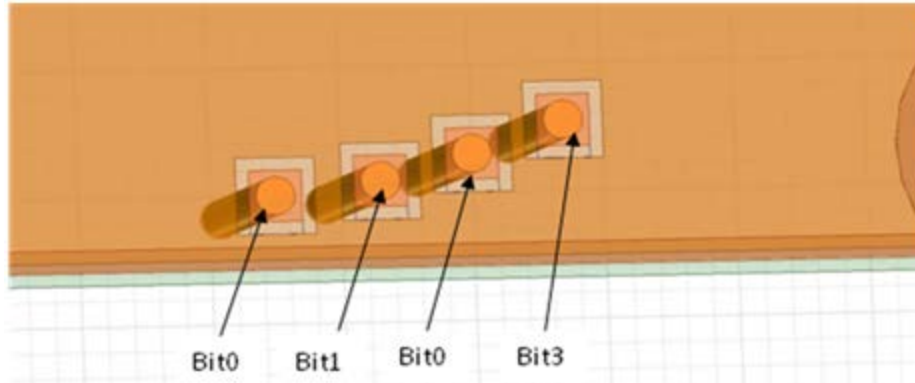


Design

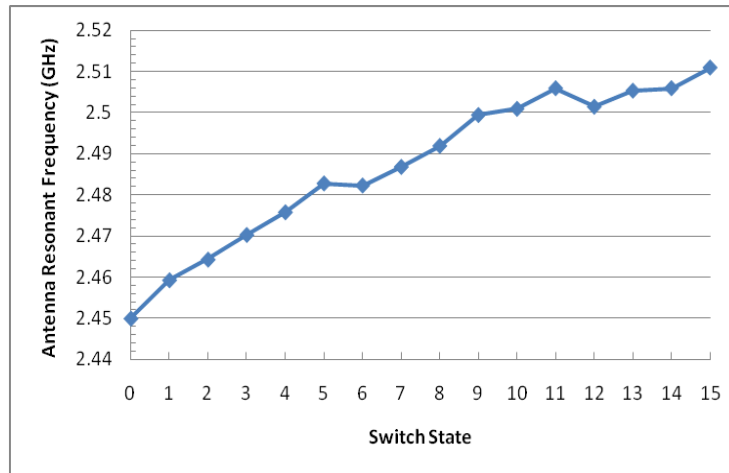


One state: 3Ω
Off State: $10K \Omega$

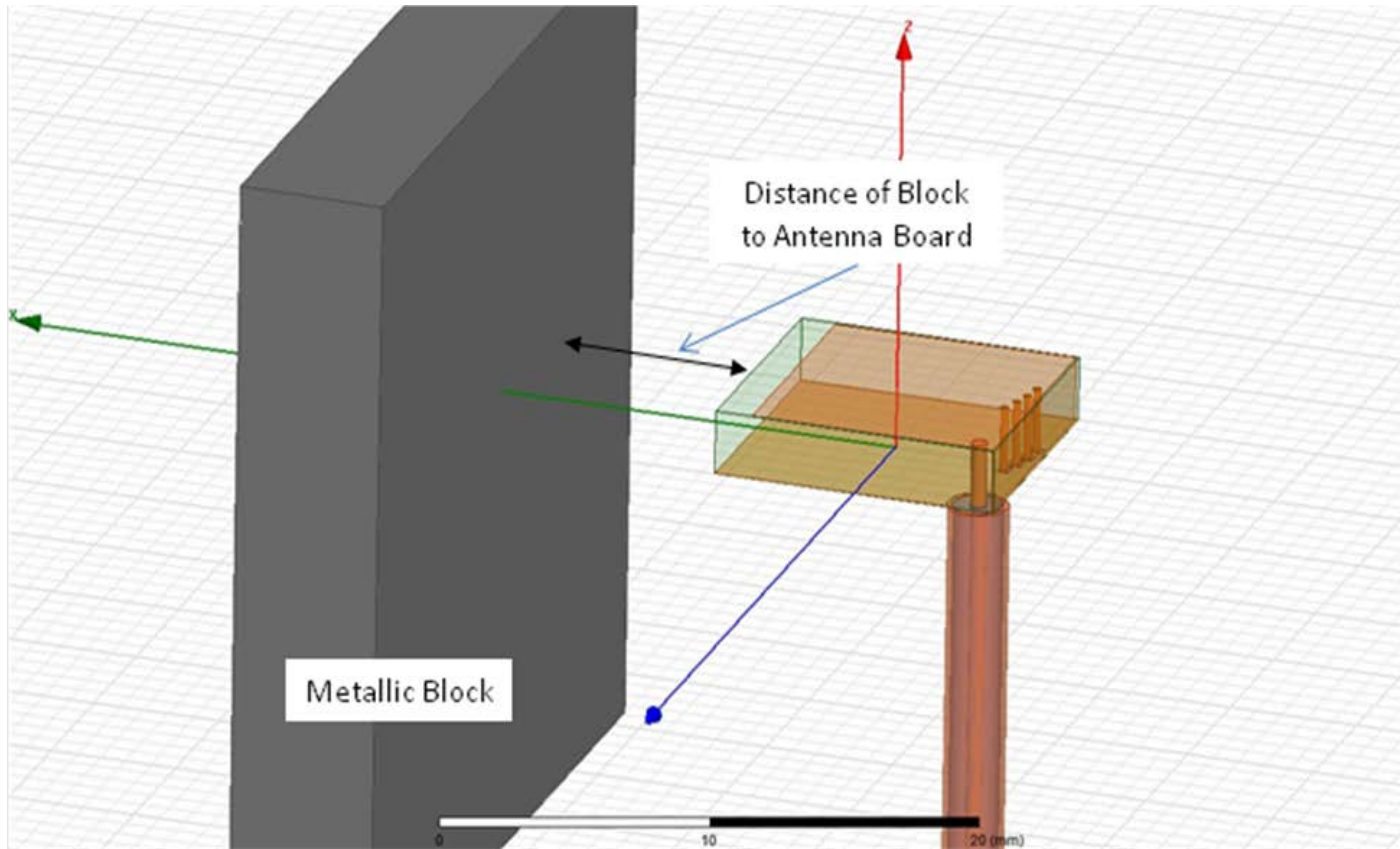
Frequency Tuning



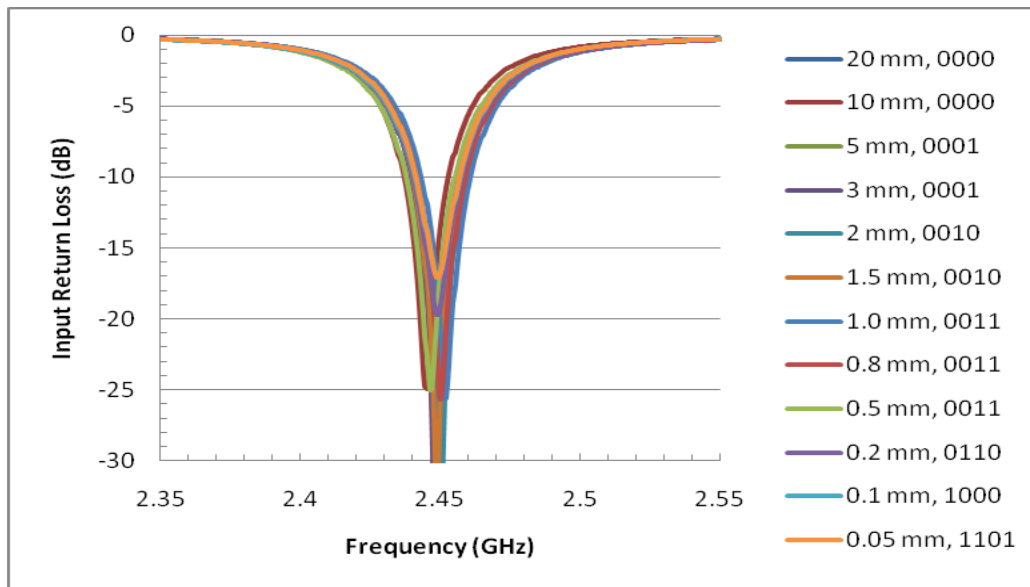
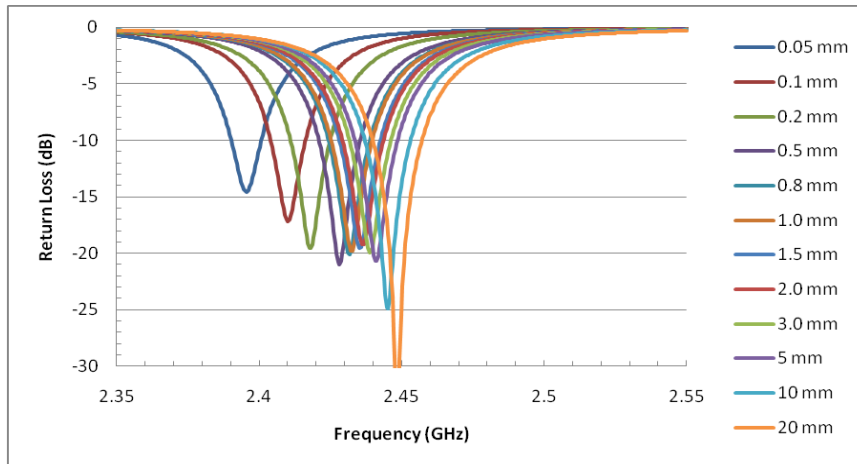
(LSB)



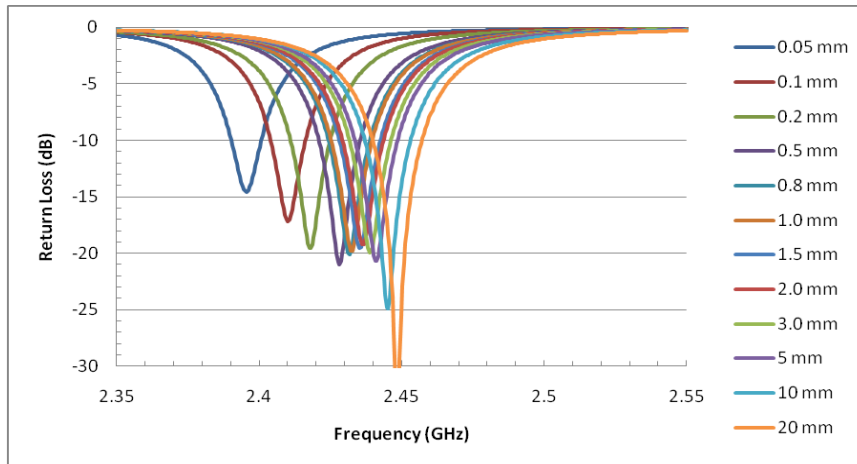
Recovering from Detuning



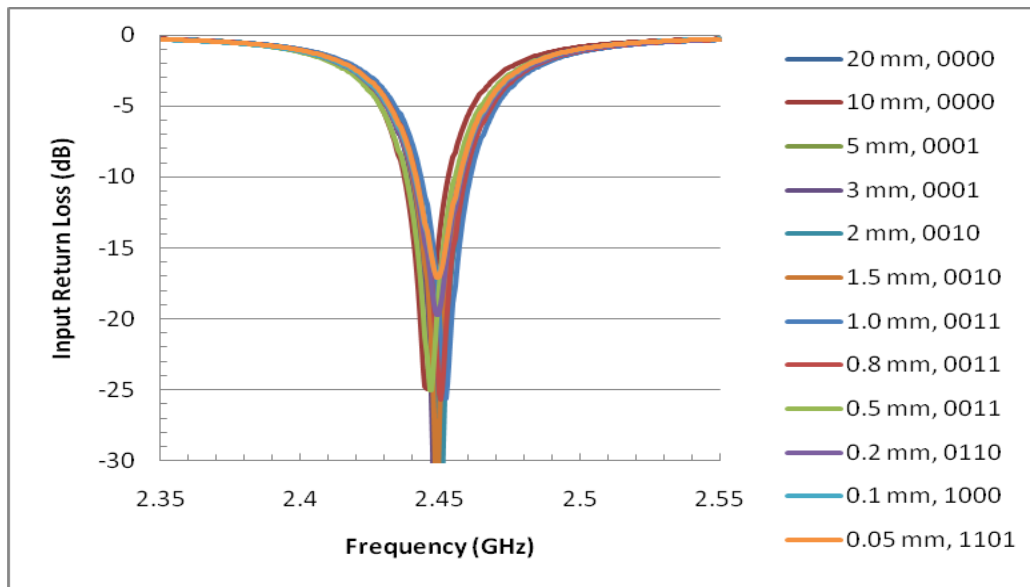
Recovering from Detuning



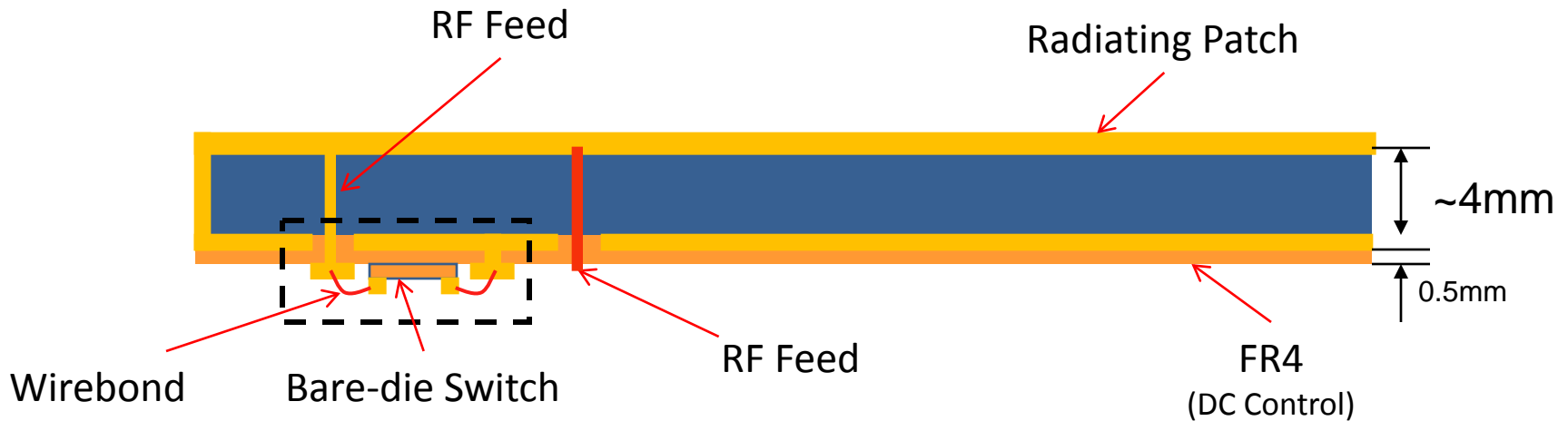
Recovering from Detuning



Block location (mm)	VSWR	Tuning State	VSWR
0.05	30.4	1101	1.3
0.1	17.2	1000	1.3
0.2	10.1	0110	1.2
0.5	5.5	0011	1.3
1.5	3.3	0010	1.1
3	2.5	0001	1.1
10	1.5	0000	1.4
20	1.1	0000	1.1



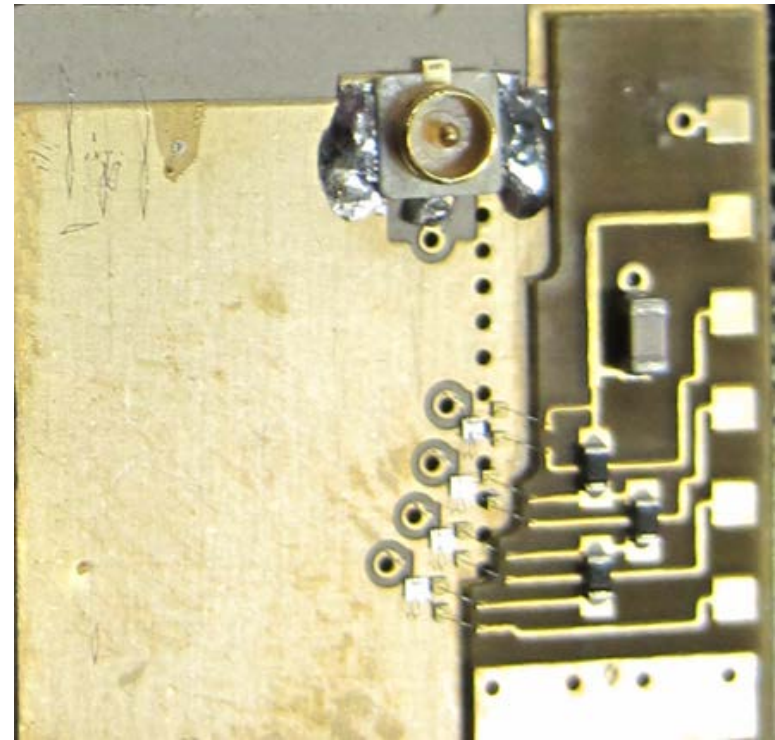
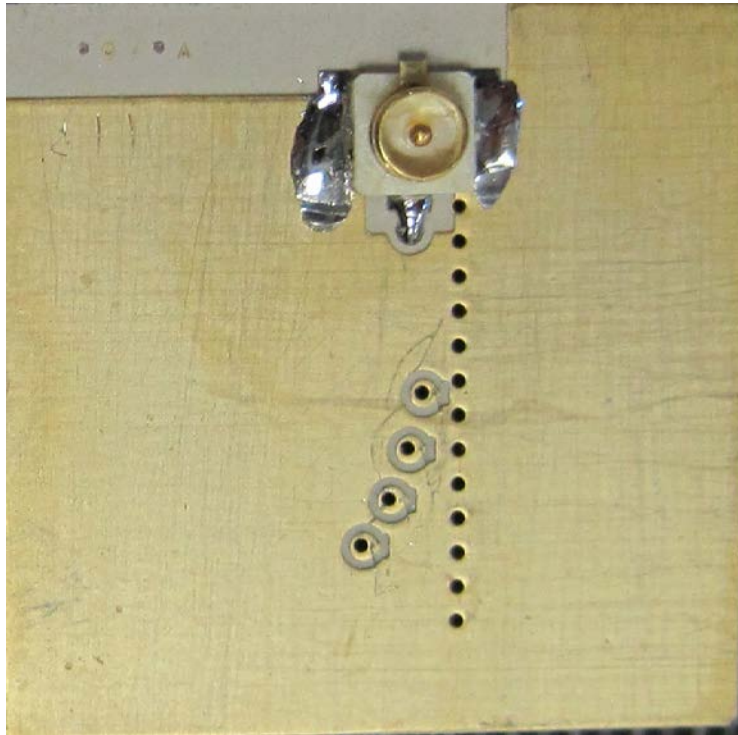
Manufacturing (*)



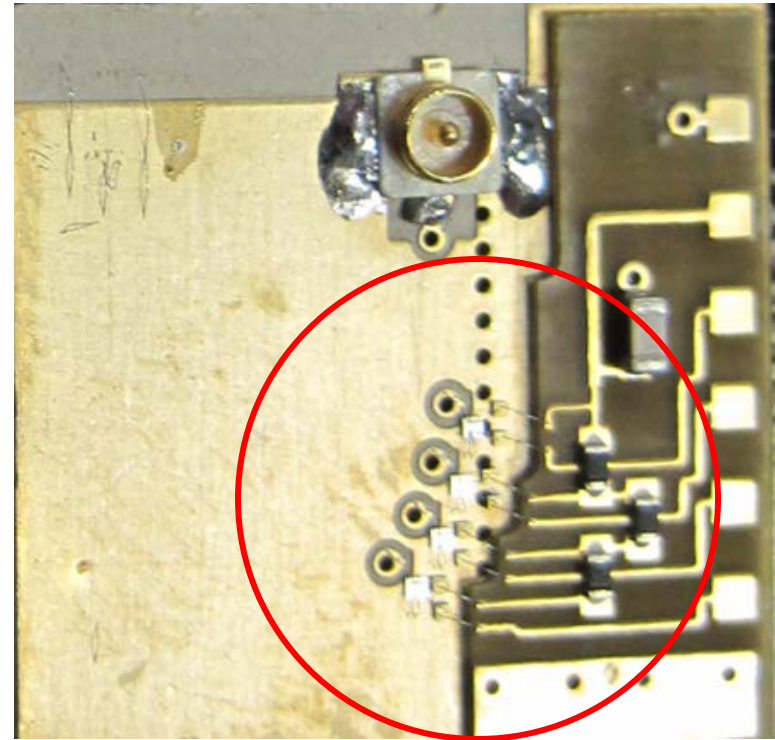
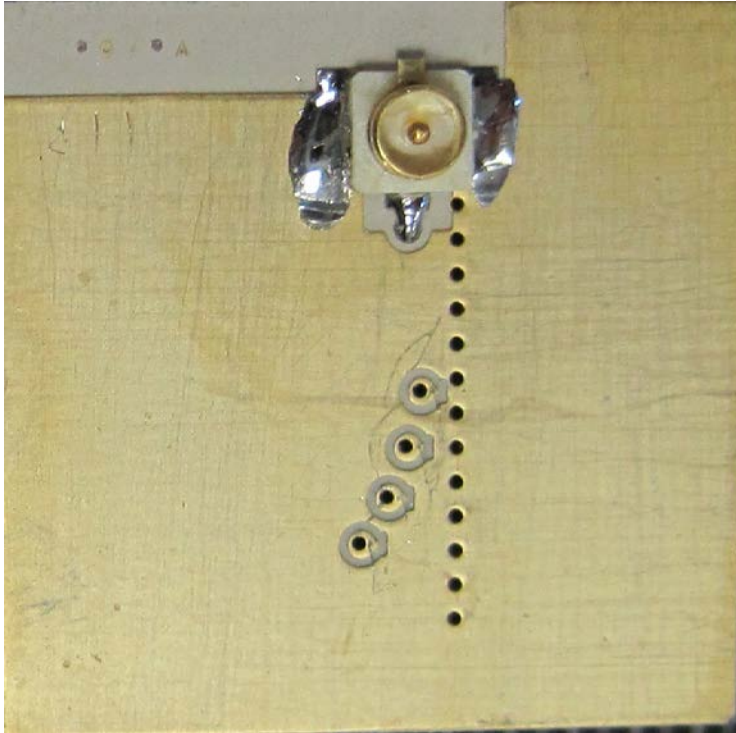
- RO3010 1/1 0.15" (3.81mm) Dk=10.2

(*) US Patent Application No. 2014/0320376A1, October 30, 2014

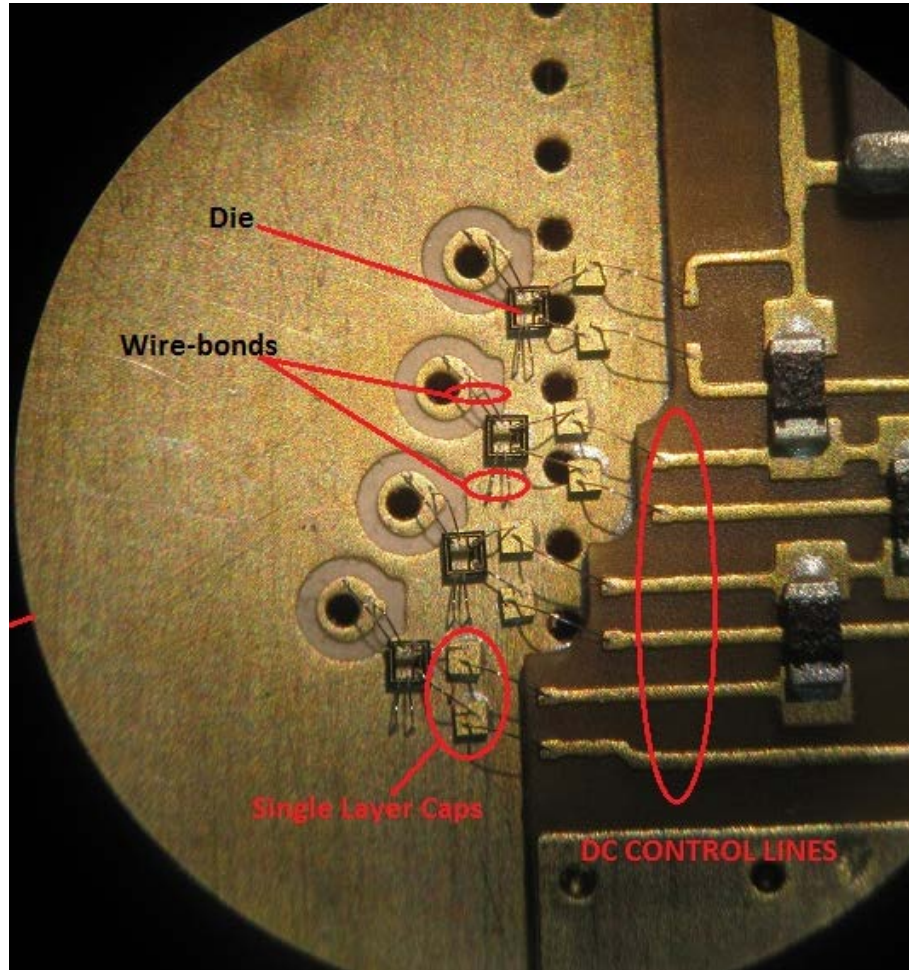
Manufacturing



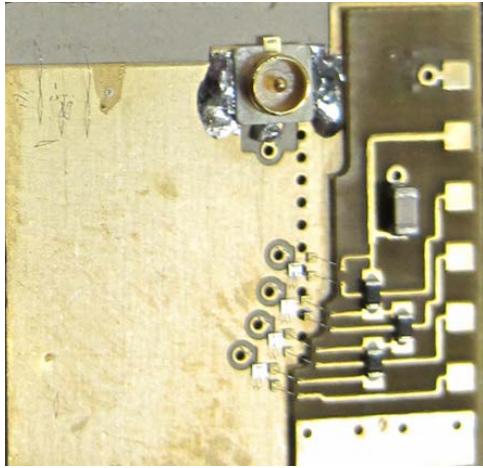
Manufacturing



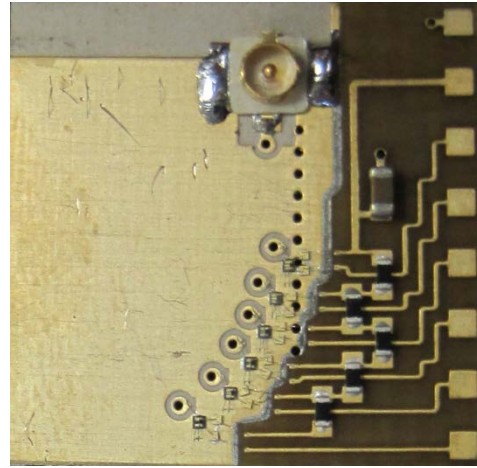
Manufacturing



4-bit and 6-bit versions



2.3 - 2.7 GHz
(16%)



2.2 - 2.9 GHz
(27%)

Finished Assembly:
16mm x 16mm x 5mm

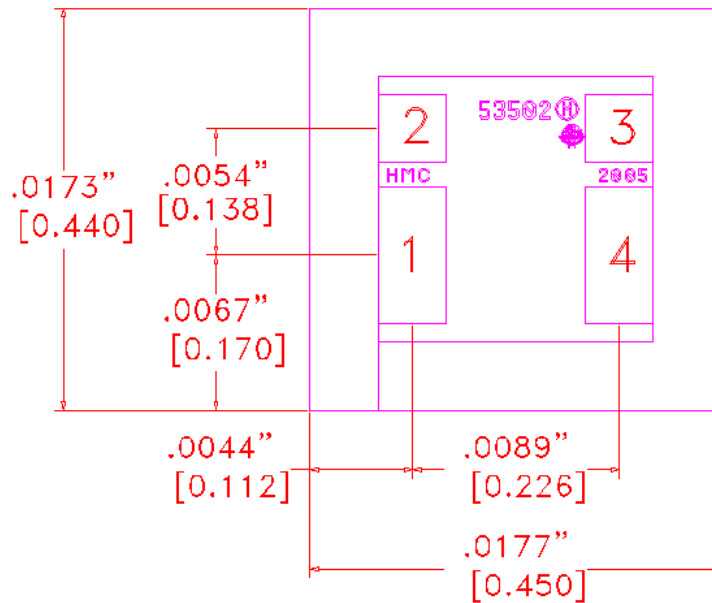
Patch Antenna:
10mm x 7mm x 4mm

GP:
13mm x 10mm

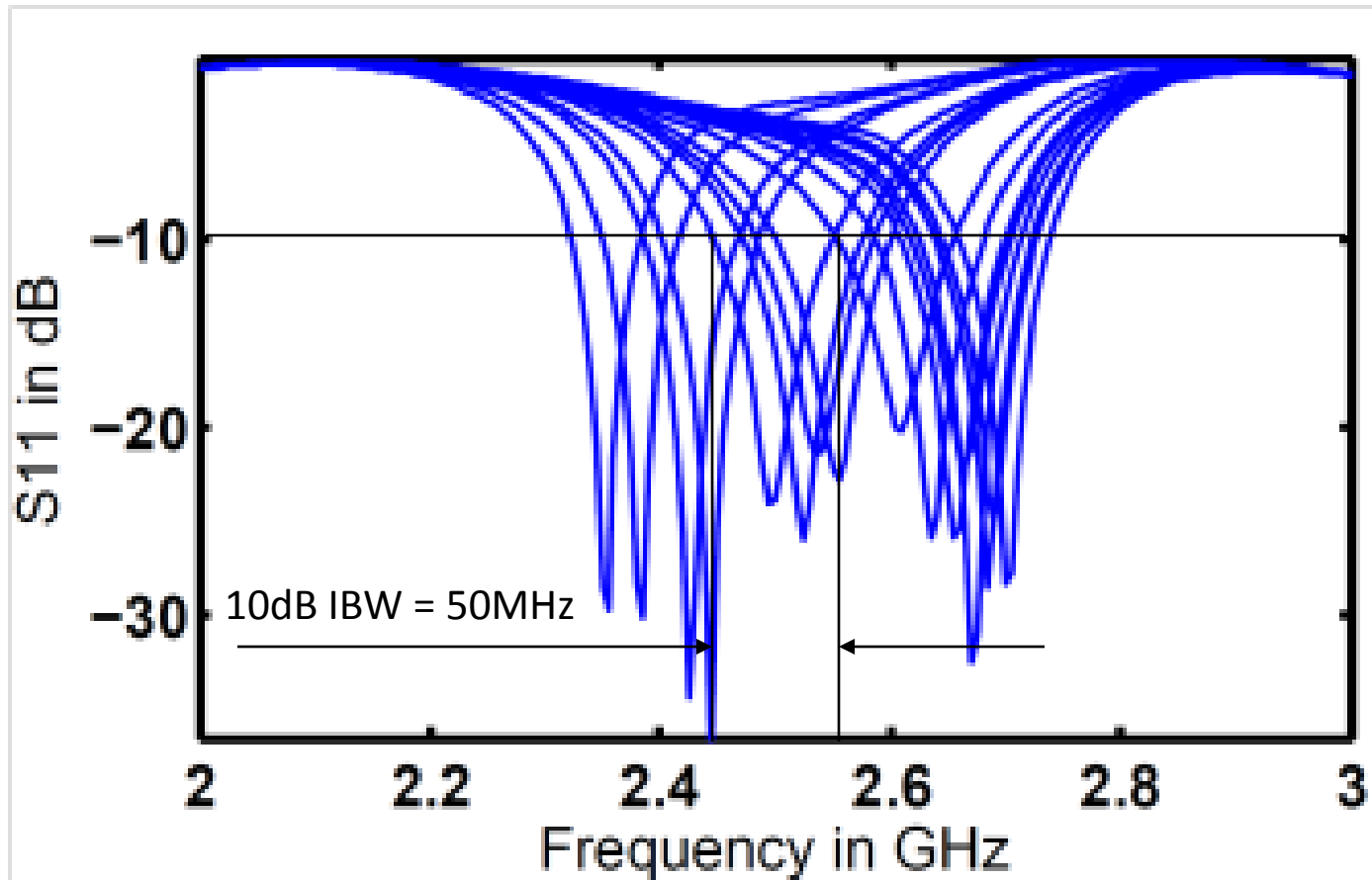


Manufacturing

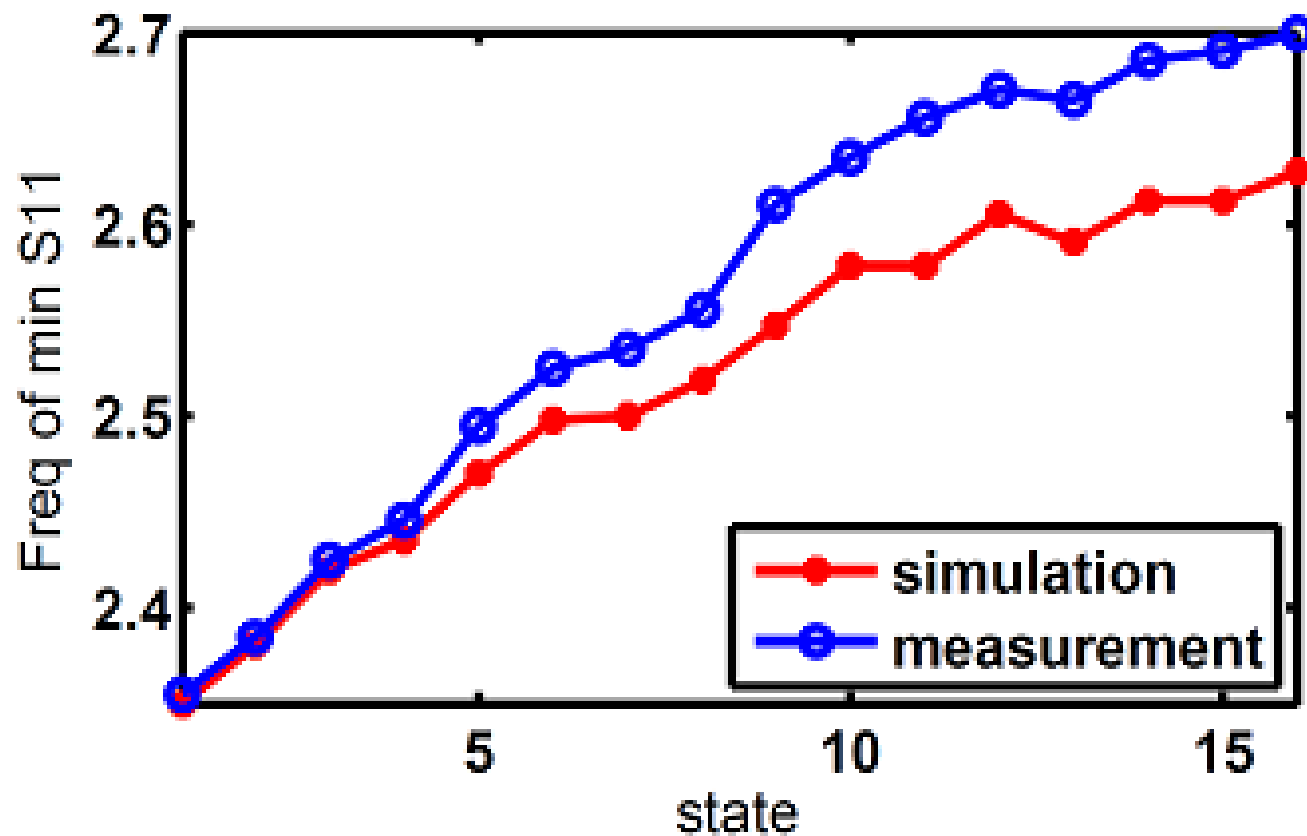
- HMC550, Hittite Microwave
- Bare Die 53502, SPST Reflective, Floating Ground
- Ron=5.9 Ohms, Coff=0.09pF
- 0.44mm x 0.45mm



Measured Data

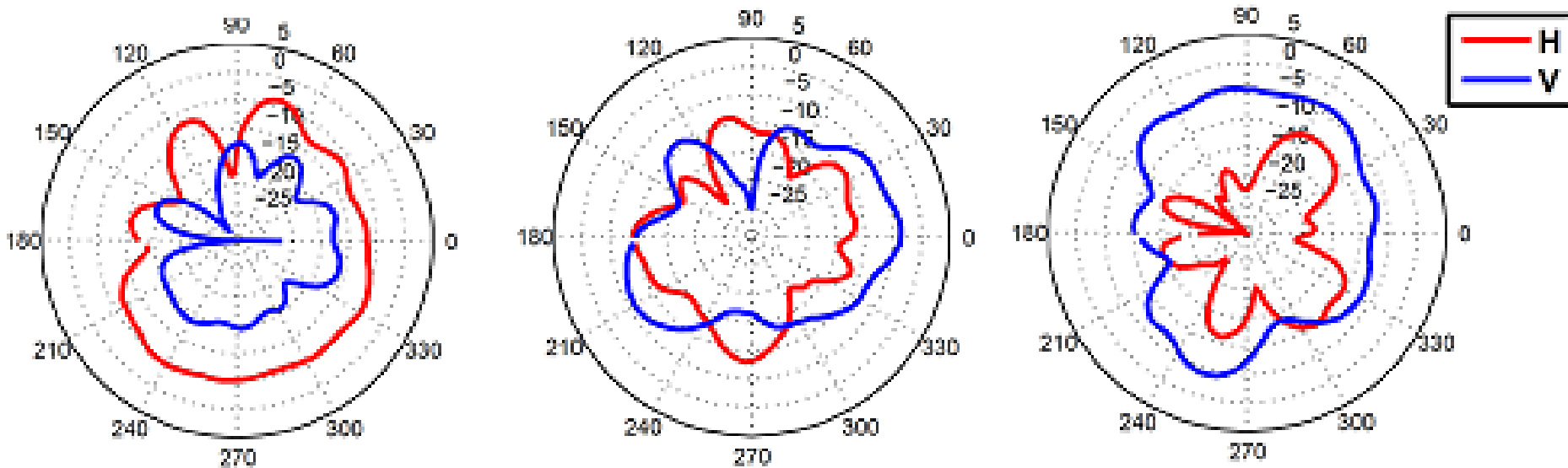


Measured Data



Measured Data

- Average Peak gain = -4.7 dBi
- High R_{on} resistance (5.9Ω) is to blame.



Enabling Technology: SPST Switches

- Solid State (GaAs or others)

- HMC550: $R_{on} \times C_{off} = 531$ fSec
- Current State of Art: 240 fSec
- 60fSec – Desired (4x Improvement)
- Non-linearity

- MEMS

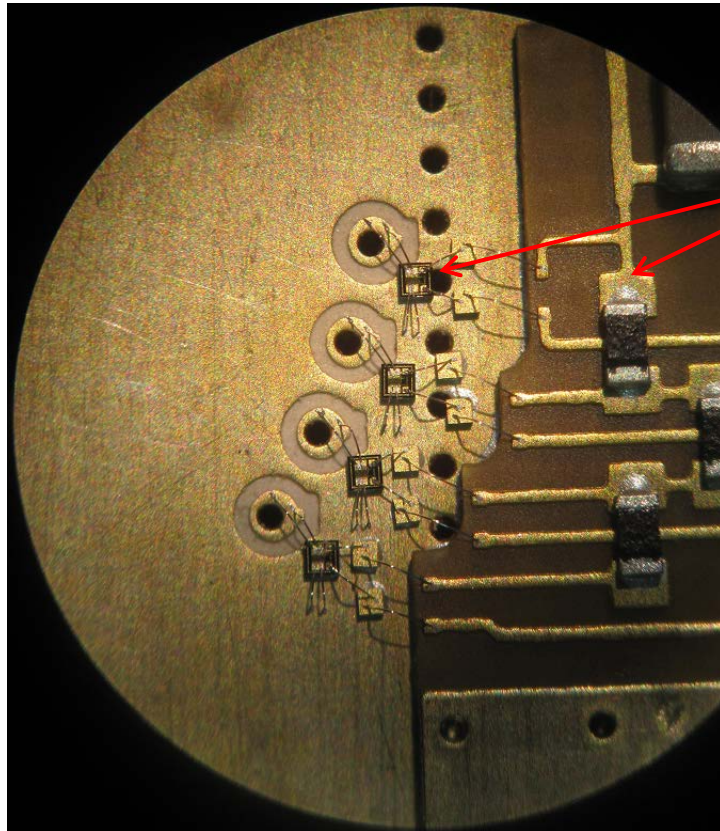
- Yield
- Cost
- Speed (μ s)
- Hot-switching

DESIRED SPECS

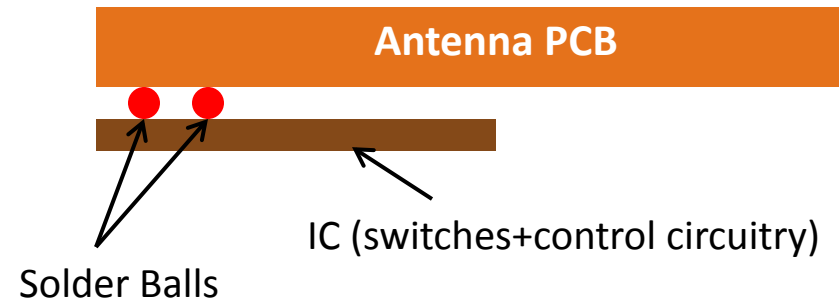
Switch Type	Bare Die, SPST, Reflective, Floating Ground
Size (mm)	0.4 x 0.4
Pad Configuration	2 DC bottom/RF opposite side (preferred)
Frequency (GHz)	0.6 – 3.0
Ron ()	2.0
Coff (Pf)	.03
RF Power (watts)	1.0
Non-Linearity (IP3)	50 dBm



Manufacturing Option: Integrated CMOS IC



Switches and the control circuitry are integrated into a thin IC



- More expensive parts but
- Less parasitics and
- Cheaper manufacturing